

- **Bidirectional Interface Between GTL+ Signal Levels and LVTTTL Logic Levels**
- **LVTTTL Interfaces Are 5-V Tolerant**
- **Identical to '16245 Function**
- **Medium-Drive GTL+ Outputs (50 mA)**
- **LVTTTL Outputs (–24 mA/24 mA)**
- **GTL+ Rise and Fall Times Designed for Optimal Data-Transfer Rate and Signal Integrity**
- **I_{off} , Power-Up 3-State, and BIAS V_{CC} Support Live Insertion**
- **Bus Hold on A-Port Data Inputs**
- **Distributed V_{CC} and GND-Pin Configuration Minimizes High-Speed Switching Noise**
- **Package Options Include Plastic Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV), and Shrink Small-Outline (DL) Packages**

NOTE: For tape and reel order entry:
 The DGGR package is abbreviated to GR, and
 the DGVR package is abbreviated to VR.

description

The SN74GTLPH16945 is a medium-drive 16-bit bus transceiver that provides LVTTTL-to-GTL+ and GTL+-to-LVTTTL signal-level translation. It is partitioned as two 8-bit transceivers and is identical to the '16245 function. The device provides a high-speed interface between cards operating at LVTTTL logic levels and a backplane operating at GTL+ signal levels. High-speed (about two times faster than standard TTL or LVTTTL) backplane operation is a direct result of GTLP's reduced output swing (<1 V), reduced input threshold levels, improved differential input, and output edge control (OEC™). Improved GTLP OEC circuits minimize bus settling time and have been designed and tested using several backplane models. The medium drive is suitable for driving double-terminated backplanes.

GTL+ is the Texas Instruments derivative of the Gunning transceiver logic (GTL) JEDEC standard JESD 8-3. The AC specification of the SN74GTLPH16945 is given only at the preferred higher noise margin GTL+, but the user has the flexibility of using this device at either GTL ($V_{TT} = 1.2$ V and $V_{REF} = 0.8$ V) or GTL+ ($V_{TT} = 1.5$ V and $V_{REF} = 1$ V) signal levels.

Normally, the B port operates at GTL or GTL+ levels, while the A-port and control inputs are compatible with LVTTTL logic levels and are 5-V tolerant. V_{REF} is the reference input voltage for the B port.

This device is fully specified for live-insertion applications using I_{off} , power-up 3-state, and BIAS V_{CC} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict. The BIAS V_{CC} circuitry precharges and preconditions the B-port input/output connections, preventing disturbance of active data on the backplane during card insertion or removal, and permits true live-insertion capability.

DGG, DGV, OR DL PACKAGE
 (TOP VIEW)

1DIR	1	48	$\overline{1OE}$
1A1	2	47	1B1
1A2	3	46	1B2
GND	4	45	GND
1A3	5	44	1B3
1A4	6	43	1B4
V_{CC}	7	42	BIAS V_{CC}
1A5	8	41	1B5
1A6	9	40	1B6
GND	10	39	GND
1A7	11	38	1B7
1A8	12	37	1B8
2A1	13	36	2B1
2A2	14	35	2B2
GND	15	34	GND
2A3	16	33	2B3
2A4	17	32	2B4
V_{CC}	18	31	V_{REF}
2A5	19	30	2B5
2A6	20	29	2B6
GND	21	28	GND
2A7	22	27	2B7
2A8	23	26	2B8
2DIR	24	25	$\overline{2OE}$

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TEXAS
 INSTRUMENTS

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description (continued)

Active bus-hold circuitry holds unused or undriven LVTTTL inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, the output-enable (\overline{OE}) input should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74GTLPH16945 is characterized for operation from -40°C to 85°C .

functional description

The SN74GTLPH16945 is a medium-drive (50 mA) 16-bit bus transceiver, providing standard '16245 functionality and is designed for asynchronous communication between data buses. The device transmits data from the A port to the B port or from the B port to the A port, depending on the logic level at the direction-control (DIR) input. \overline{OE} can be used to disable the device so the buses are effectively isolated. Data polarity is noninverting.

For A-to-B data flow, when \overline{OE} is low and DIR is high, the B outputs take on the logic value of the A inputs. When \overline{OE} is high, the outputs are in the high-impedance state.

Data flow for B to A is similar to that for A to B, but \overline{OE} is low and DIR is low.

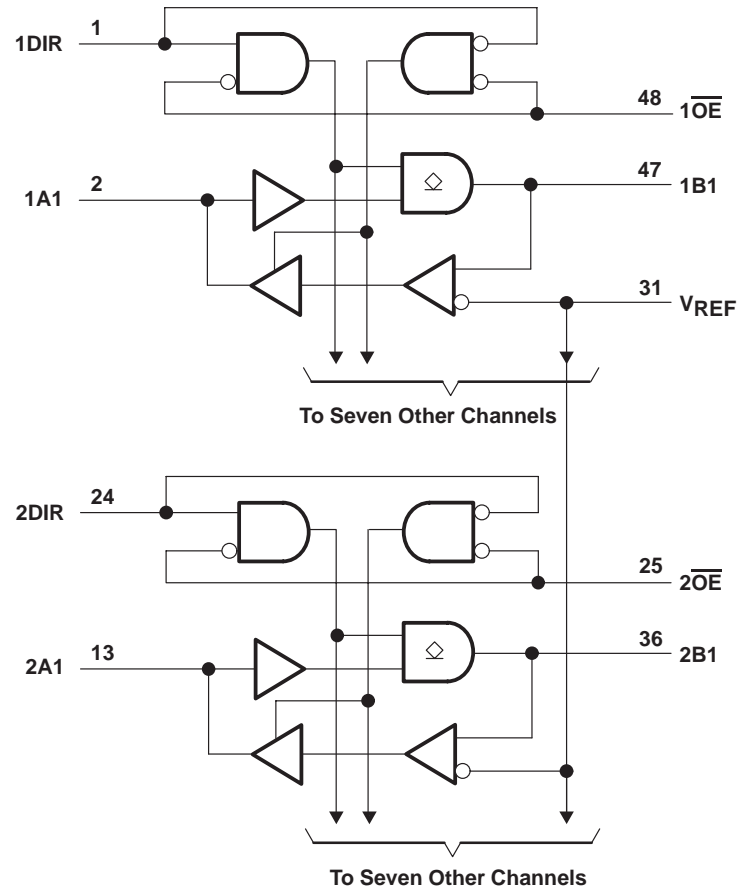
FUNCTION TABLE

INPUTS		OUTPUT	MODE
\overline{OE}	DIR		
L	L	B data to A port	Transparent
L	H	A data to B port	Transparent
H	X	Z	Isolation

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logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC} and BIAS V_{CC}	–0.5 V to 4.6 V
Input voltage range, V_I (see Note 1): A-port and control inputs	–0.5 V to 7 V
B port and V_{REF}	–0.5 V to 4.6 V
Voltage range applied to any output in the high-impedance or power-off state, V_O	
(see Note 1): A port	–0.5 V to 7 V
B port	–0.5 V to 4.6 V
Current into any output in the low state, I_O : A port	48 mA
B port	100 mA
Current into any A-port output in the high state, I_O (see Note 2)	48 mA
Continuous current through each V_{CC} or GND	±100 mA
Input clamp current, I_{IK} ($V_I < 0$)	–50 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Package thermal impedance, θ_{JA} (see Note 3): DGG package	70°C/W
DGV package	58°C/W
DL package	63°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
 3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Notes 4 through 6)

			MIN	NOM	MAX	UNIT
V _{CC} , BIAS V _{CC}	Supply voltage		3.15	3.3	3.45	V
V _{TT}	Termination voltage	GTL	1.14	1.2	1.26	V
		GTL+	1.35	1.5	1.65	
V _{REF}	Supply voltage	GTL	0.74	0.8	0.87	V
		GTL+	0.87	1	1.1	
V _I	Input voltage	B port	V _{TT}			V
		Except B port	V _{CC}			
V _{IH}	High-level input voltage	B port	V _{REF} +0.05			V
		Except B port	2			
V _{IL}	Low-level input voltage	B port	V _{REF} –0.05			V
		Except B port	0.8			
I _{IK}	Input clamp current		–18			mA
I _{OH}	High-level output current	A port	–24			mA
I _{OL}	Low-level output current	A port	24			mA
		B port	50			
T _A	Operating free-air temperature		–40	85		°C

- NOTES: 4. All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
 5. Normal connection sequence is GND first, BIAS $V_{CC} = 3.3$ V second, and $V_{CC} = 3.3$ V, I/O, control inputs, V_{TT} and V_{REF} (any order) last. However, if the B-port I/O precharge is not required, the acceptable connection sequence is GND first and $V_{CC} = 3.3$ V, BIAS $V_{CC} = 3.3$ V, I/O, control inputs, V_{TT} and V_{REF} (any order) last. When V_{CC} is connected, the BIAS V_{CC} circuitry is disabled.
 6. V_{TT} and R_{TT} can be adjusted to accommodate backplane impedances as long as they do not exceed the DC absolute I_{OL} ratings. Similarly, V_{REF} can be adjusted to optimize noise margins, but normally is $2/3 V_{TT}$.

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electrical characteristics over recommended operating free-air temperature range for GTL+ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V _{IK}		V _{CC} = 3.15 V, I _I = −18 mA				−1.2	V
V _{OH}	A port	V _{CC} = 3.15 V to 3.45 V, I _{OH} = −100 μA		V _{CC} −0.2			V
		V _{CC} = 3.15 V, I _{OH} = −12 mA		2.4			
		I _{OH} = −24 mA		2			
V _{OL}	A port	V _{CC} = 3.15 V to 3.45 V, I _{OL} = 100 μA				0.2	V
		I _{OL} = 12 mA				0.4	
		I _{OL} = 24 mA				0.5	
	B port	V _{CC} = 3.15 V to 3.45 V, I _{OL} = 100 μA				0.2	
		I _{OL} = 10 mA				0.2	
		I _{OL} = 40 mA				0.4	
I _{OL} = 50 mA				0.55			
I _I ‡	B port	V _{CC} = 3.45 V, V _I = 0 to 1.5 V				±10	μA
	A-port and control inputs	V _{CC} = 3.45 V, V _I = 0 or V _{CC}				±10	
		V _I = 5.5 V				±20	
I _{BHL} §	A port	V _{CC} = 3.15 V, V _I = 0.8 V		75			μA
I _{BHH} ¶	A port	V _{CC} = 3.15 V, V _I = 2 V		−75			μA
I _{BHLO} #	A port	V _{CC} = 3.45 V, V _I = 0 to V _{CC}				500	μA
I _{BHHO}	A port	V _{CC} = 3.45 V, V _I = 0 to V _{CC}				−500	μA
I _{CC}	A or B port	V _{CC} = 3.45 V, I _O = 0, V _I (A-port or control input) = V _{CC} or GND V _I (B port) = V _{TT} or GND	Outputs high			50	mA
			Outputs low			50	
			Outputs disabled			50	
ΔI _{CC} ☆		V _{CC} = 3.45 V, One A-port or control input at V _{CC} − 0.6 V, Other A-port or control inputs at V _{CC} or GND				1	mA
C _i	Control inputs	V _I = 3.15 V or 0					pF
C _{io}	A port	V _O = 3.15 V or 0					pF
	B port	V _O = 1.5 V or 0					

† All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ For I/O ports, the parameter I_I includes the off-state output leakage current.

§ The bus-hold circuit can sink at least the minimum low sustaining current at $V_{IL\text{max}}$. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to $V_{IL\text{max}}$.

¶ The bus-hold circuit can source at least the minimum high sustaining current at $V_{IH\text{min}}$. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to $V_{IH\text{min}}$.

An external driver must source at least I_{BHLO} to switch this node from low to high.

|| An external driver must sink at least I_{BHHO} to switch this node from high to low.

☆ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

live-insertion specifications for A port over recommended operating free-air temperature range

PARAMETER	TEST CONDITIONS			MIN	MAX	UNIT
I_{off}	$V_{CC} = 0$,	BIAS $V_{CC} = 0$,	V_I or $V_O = 0\text{ to }5.5\text{ V}$		100	μA
I_{OZPU}	$V_{CC} = 0\text{ to }1.5\text{ V}$,	$V_O = 0.5\text{ V to }3\text{ V}$,	$\overline{OE} = 0$		± 100	μA
I_{OZPD}	$V_{CC} = 1.5\text{ V to }0$,	$V_O = 0.5\text{ V to }3\text{ V}$,	$\overline{OE} = 0$		± 100	μA

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live-insertion specifications for B port over recommended operating free-air temperature range

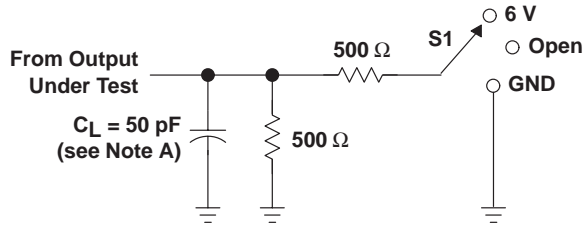
PARAMETER	TEST CONDITIONS			MIN	MAX	UNIT
I_{off}	$V_{CC} = 0$,	BIAS $V_{CC} = 0$,	V_I or $V_O = 0$ to 1.5 V		100	μA
I_{OZPU}	$V_{CC} = 0$ to 1.5 V,	$V_O = 0.5$ V to 1.5 V,	$\overline{OE} = 0$		± 100	μA
I_{OZPD}	$V_{CC} = 1.5$ V to 0,	$V_O = 0.5$ V to 1.5 V,	$\overline{OE} = 0$		± 100	μA
I_{CC} (BIAS V_{CC})	$V_{CC} = 0$ to 3.15 V	BIAS $V_{CC} = 3.15$ V to 3.45 V,	V_O (B port) = 0 to 1.5 V		5	mA
	$V_{CC} = 3.15$ V to 3.45 V				10	μA
V_O	$V_{CC} = 0$,	BIAS $V_{CC} = 3.3$ V		0.95	1.05	V
I_O	$V_{CC} = 0$,	BIAS $V_{CC} = 3.15$ V to 3.45 V,	V_O (B port) = 0.6 V	-1		μA

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.5$ V and $V_{REF} = 1$ V for GTL+ (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP†	MAX	UNIT
t _{pd}	A	B				ns
t _{en}	\overline{OE}	B				ns
t _{dis}						
t _r	Rise time, B outputs (0.6 V to 1.3 V)					ns
t _f	Fall time, B outputs (1.3 V to 0.6 V)					ns
t _{pd}	B	A				ns
t _{en}	\overline{OE}	A				ns
t _{dis}						

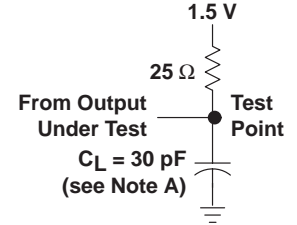
† All typical values are at $V_{CC} = 3.3$ V, $T_A = 25^\circ C$.

PARAMETER MEASUREMENT INFORMATION

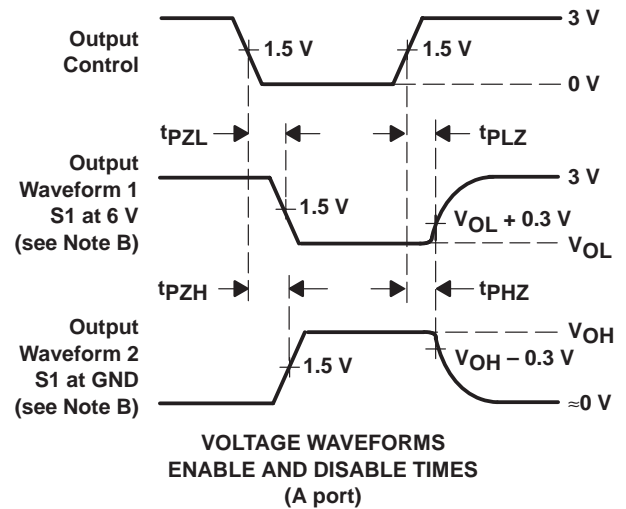
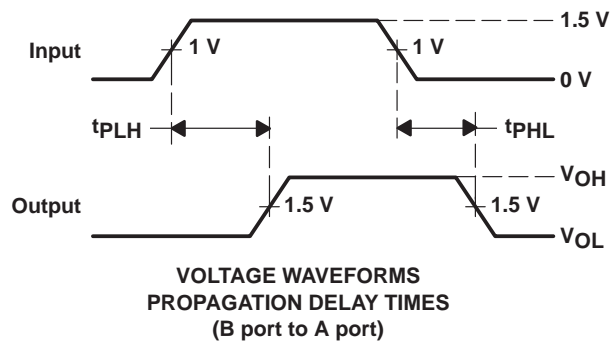
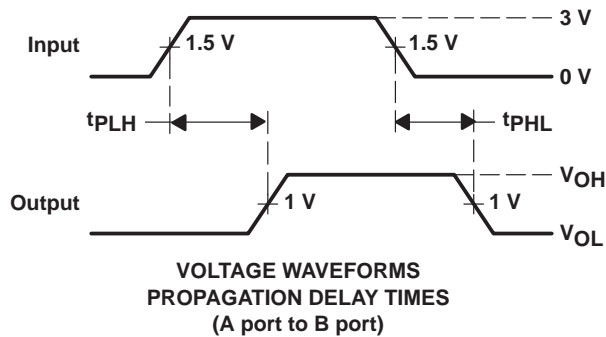


LOAD CIRCUIT FOR A OUTPUTS

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND



LOAD CIRCUIT FOR B OUTPUTS



- NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10$ MHz, $Z_O = 50 \Omega$, $t_r \leq 2.5$ ns, $t_f \leq 2.5$ ns.
D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

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DISTRIBUTED-LOAD BACKPLANE SWITCHING CHARACTERISTICS

This data sheet is specified for and tested to the lump load shown in Figure 1. However, the designer probably uses this GTLP device in a distributed load like that shown in Figure 2, in which actual B-port backplane switching characteristics are different. Therefore, the device is modeled as shown in Figure 3, which very closely matches the results obtained using Figure 2. Switching characteristics based on Figure 3 more closely match actual backplane design requirements.

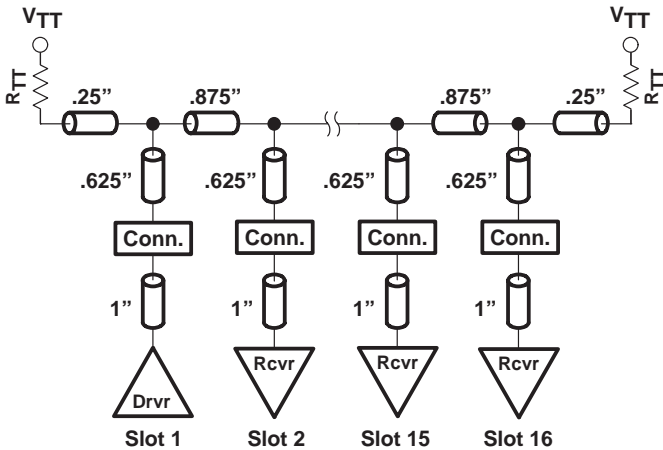


Figure 2. Test Backplane Model

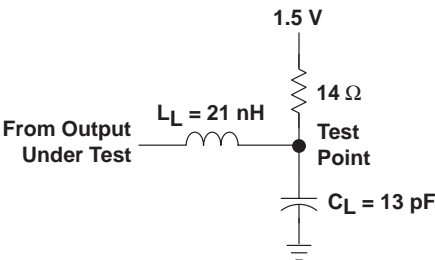


Figure 3. Distributed-Load Circuit for B Outputs

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $V_{TT} = 1.5\text{ V}$ and $V_{REF} = 1\text{ V}$ for GTL+ (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	TYP†	MAX	UNIT
t _{pd}	A	B				ns
t _{en}	OE	B				ns
t _{dis}						
t _r	Rise time, B outputs (0.6 V to 1.3 V)					ns
t _f	Fall time, B outputs (1.3 V to 0.6 V)					ns

† All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

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